



60V N-CHANNEL ENHANCEMENT MODE MOSFET POWERDI®

Product Summary

V _{(BR)DSS}	R _{DS(ON)}	I _D T _C = +25°C	
60V	$15m\Omega @ V_{GS} = 10V$	32 A	
00 V	$24m\Omega$ @ $V_{GS} = 4.5V$	24 A	

Description

This MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) and maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

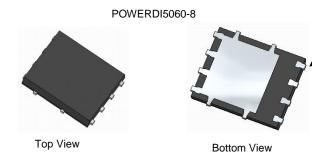
- Load Switch
- Adaptor Switch
- Notebook PC

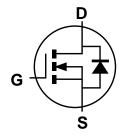
Features

- Thermally Efficient Package Cooler Running Applications
- High Conversion Efficiency
- Low RDS(ON) Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

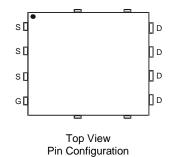
Mechanical Data

- Case: POWERDI5060-8
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Weight: 0.097 grams (Approximate)





Internal Schematic



Ordering Information (Note 4)

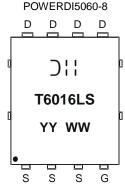
Part Number	Case	Packaging
DMT6016LPS-13	POWERDI5060-8	2,500 / Tape & Reel

Pin1

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



Dili=Manufacturer's Marking
T6016LS = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Digit of Year (ex: 14 = 2014)
WW = Week Code (01 to 53)



Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V_{DSS}	60	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Dunin Comment (Note C) // 401/	Steady State	$T_C = +25$ °C $T_C = +70$ °C	I _D	32 25	А
Continuous Drain Current (Note 6) V _{GS} = 10V	t < 10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	14.8 11.9	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I _{DM}	60	Α		
Maximum Continuous Body Diode Forward Current (Note 6)			I _S	2	Α
Avalanche Current (Note 8) L = 0.1mH			I _{AS}	15.3	Α
Avalanche Energy (Note 8) L = 0.1mH			Eas	11.7	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Units	
Total Power Dissipation (Note 5)		P_D	1.23	W	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	_	102	°C/W	
Thermal Resistance, Junction to Ambient (Note 3)	t<10s	$R_{\theta JA}$	52	C/VV	
Total Power Dissipation (Note 6)		P_D	2.7	W	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	ס	49	°C/W	
Internal Resistance, Junction to Ambient (Note o)	t<10s	$R_{\theta JA}$	24		
Thermal Resistance, Junction to Case (Note 7)		$R_{ heta JC}$	4.8	°C/W	
Operating and Storage Temperature Range		$T_{J,}T_{STG}$	-55 to +150	°C	

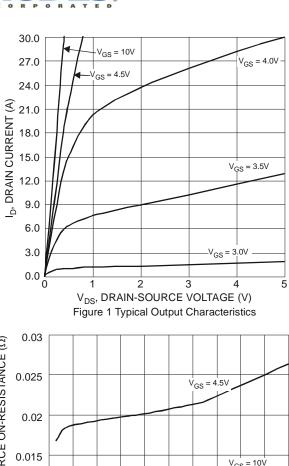
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

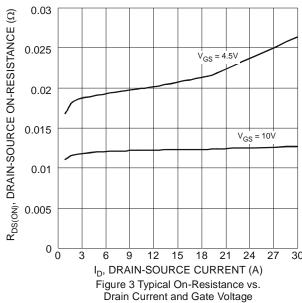
Ob and a facility	0	14:	T		1114	To al O an dition	
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)			T	T		1	
Drain-Source Breakdown Voltage	BV _{DSS}	60	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 48V$, $V_{GS} = 0V$	
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	$V_{GS(th)}$	1	_	2.5	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance	D	_	_	15	mΩ	$V_{GS} = 10V, I_D = 20A$	
Static Diain-Source Off-Resistance	R _{DS (ON)}	_	_	24	11122	$V_{GS} = 4.5V, I_D = 18A$	
Diode Forward Voltage	V_{SD}	_	0.7	1.2	V	V _{GS} = 0V, I _S = 1A	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	C _{iss}	_	864	_		$V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz	
Output Capacitance	Coss	_	282	_	pF		
Reverse Transfer Capacitance	C _{rss}	_	27	_			
Gate Resistance	R _G	_	1.3	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	8.4	_			
Total Gate Charge (V _{GS} = 10V)	Qg	_	17	_	nC	V _{DS} = 30V. I _D = 10A	
Gate-Source Charge	Q_{gs}	_	3.1	_	110	VDS = 30V, ID = 10A	
Gate-Drain Charge	Q_{gd}	_	4.3	_			
Turn-On Delay Time	t _{D(on)}	_	3.4	_			
Turn-On Rise Time	t _r	_	5.2	_		$V_{GS} = 10V, V_{DS} = 30V,$	
Turn-Off Delay Time	t _{D(off)}	_	13	_	ns	$R_G = 6\Omega$, $I_D = 10A$	
Turn-Off Fall Time	tf	_	7	_			
Reverse Recovery Time	t _{rr}	_	22	_	ns	1 400 4:/44 4000/	
Reverse Recovery Charge	Qrr	_	11	_	$_{\text{nC}}$ I _F = 10A, di/dt = 100A/µs		

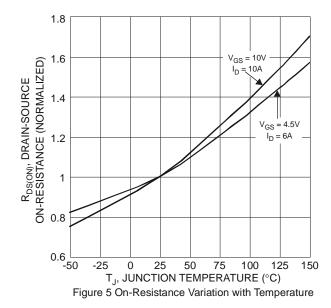
Notes:

- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.
 7. Thermal resistance from junction to soldering point (on the exposed drain pad).
 8. I_{AS} and E_{AS} rating are based on low frequency and duty cycles to keep T_J = +25°C.
 9. Short duration pulse test used to minimize self-heating effect.
 10. Guaranteed by design. Not subject to product testing.

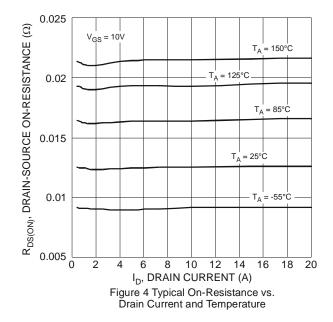








30 $V_{DS} = 5.0V$ 27 24 ID, DRAIN CURRENT (A) 21 18 15 12 9 $T_A =$ T_A = 85°C 6 T_A = 125°C T_A = 25°C 3 = -55°C 0 L 1.5 2 2.5 3 3.5 4 4. V_{GS}, GATE-SOURCE VOLTAGE (V) 4.5 5 Figure 2 Typical Transfer Characteristics



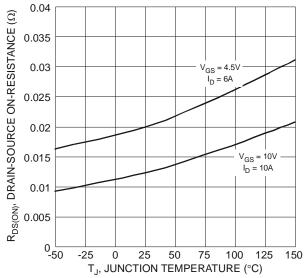


Figure 6 On-Resistance Variation with Temperature



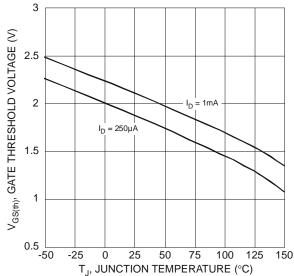


Figure 7 Gate Threshold Variation vs. Ambient Temperature

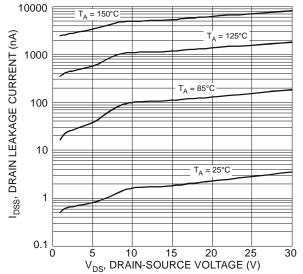
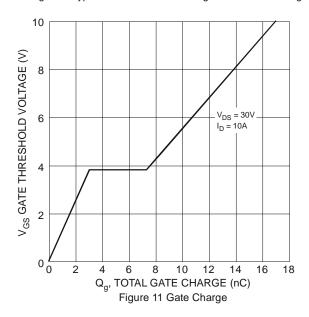
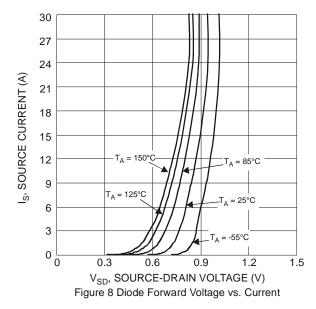
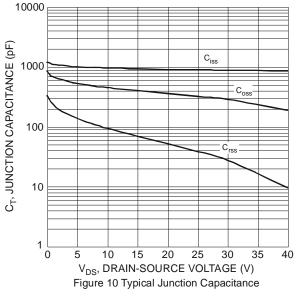
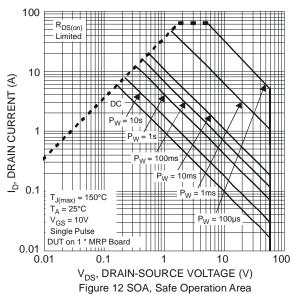


Figure 9 Typical Drain-Source Leakage Current vs. Voltage

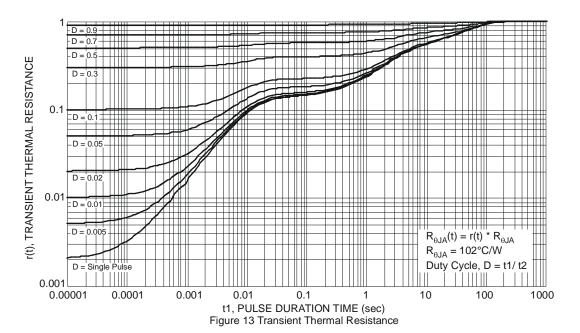










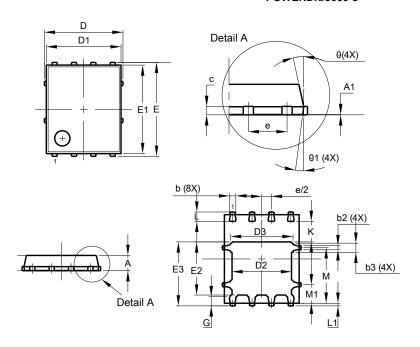




Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

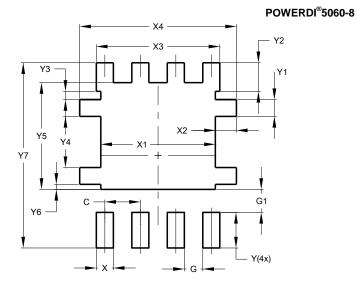
POWERDI®5060-8



POWERDI®5060-8					
Dim	Min	Тур			
Α	0.90	1.10	1.00		
A1	0.00	0.00 0.05			
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D	;	5.15 BSC	;		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90 4.30 4.10				
Е	(6.15 BSC	;		
E1	5.60	6.00	5.80		
E2	3.28	8 3.68			
E3	3.99 4.39 4.19				
е	1.27 BSC				
G	0.51	0.71	0.61		
K	0.51				
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12º	11º		
Θ1	6º	8º	7º		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)			
С	1.270			
G	0.660			
G1	0.820			
Х	0.610			
X1	4.100			
X2	0.755			
Х3	4.420			
X4	5.610			
Υ	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
Y7	6.610			



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